VS-8ETL06SHM3



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Ultralow V_F Hyperfast Rectifier for Discontinuous Mode PFC, 8 A FRED Pt[®]



PRIMARY CHARACTERISTICS								
I _{F(AV)}	8 A							
V _R	600 V							
V _F at I _F	0.81 V							
t _{rr} typ.	60 ns							
T _J max.	175 °C							
Package	D ² PAK (TO-263AB)							
Circuit configuration	Single							

FEATURES

- Benchmark ultralow forward voltage drop
- Hyperfast recovery time
- · Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meets JESD 201 class 1 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

State of the art, ultralow V_F , soft-switching hyperfast rectifiers optimized for discontinuous (critical) mode (DCM) power factor correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Peak repetitive reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 160 °C	8							
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	175	А						
Peak repetitive forward current	I _{FM}		16							
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-					
Forward voltage	V _F	I _F = 8 A	-	0.96	1.05	V				
Forward voltage		I _F = 8 A, T _J = 150 °C	-	0.81	0.86					
Deverae leakage everent		$V_{R} = V_{R}$ rated	-	0.05	5					
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	100	μΑ				
Junction capacitance	CT	V _R = 600 V	-	17	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t$	= 100 A/µs, V _R = 30 V	-	60	100				
Reverse recovery time	+	$I_F = 8 \text{ A}, \text{ d}I_F/\text{d}t$	= 100 A/µs, V _R = 30 V	-	150	250	20			
	t _{rr}	$T_J = 25 \ ^\circ C$		-	170	-	ns			
		T _J = 125 °C		-	250	-				
Poole recovery ourrent		T _J = 25 °C	l _F = 8 A dl _F /dt = 200 A/µs	-	15	-	А			
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 390 \text{ V}$	-	20	-	A			
Povereo recovery charge	0	T _J = 25 °C		-	1.3	-				
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	2.6	-	μC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	1.4	2					
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-					
Woight			-	2.0	-	g				
Weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style D ² PAK (TO-263AB)	8ETL06SH							

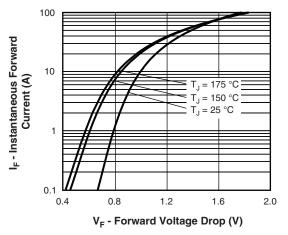


Fig. 1 - Typical Forward Voltage Drop Characteristics

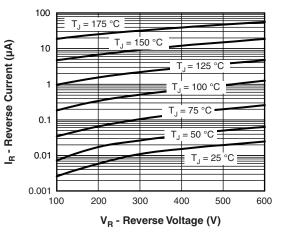


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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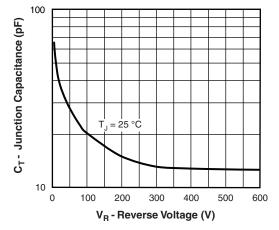


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

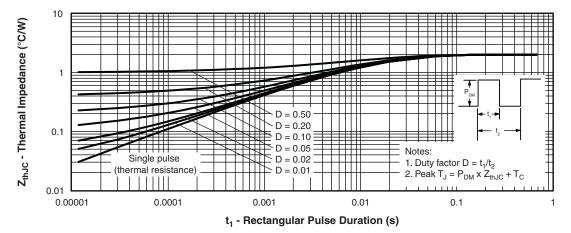
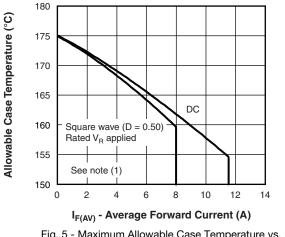
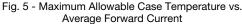
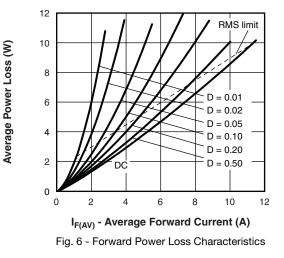


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics









(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = rated V_R$

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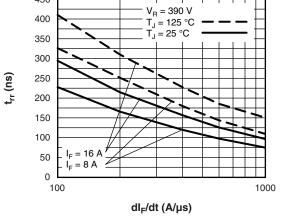
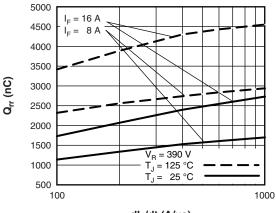


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



dl_F/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl_F/dt

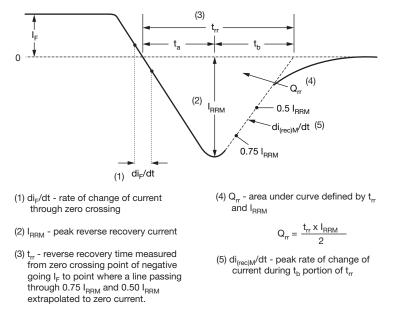


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code	VS-	8	Е	т	L	06	S	TRL	н	М3	
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)	(10)	
			<u> </u>		0		\bigcirc	\bigcirc	\bigcirc	\bigcirc	
	면 ·		-	niconduc	•	oduct					
	2 -	2 - Current rating (8 A)									
	3 -	- E = single diode									
	4 -	- Т=	T = TO-220, D ² PAK								
	5 -	L =	ultralow	V _F hyp	erfast re	covery					
	6 -	Volt	tage rati	ng (06 =	= 600 V))					
	7 -	• S	= D ² PA	K							
	8 -	• N	one = tu	be (50 r	pieces)						
			 None = tube (50 pieces) TRL = tape and reel (left oriented, for D²PAK package) 								
		• TRR = tape and reel (right oriented, for D ² PAK package)									
	9 -	H =	lead (P	b)-free							
	10 -	M3	= halog	en-free,	RoHS-0	complia	nt, and	termina	tions lea	ad (Pb)-i	

ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8ETL06SHM3	50	1000	Antistatic plastic tube						
VS-8ETL06STRRHM3	800	800	13" diameter reel						
VS-8ETL06STRLHM3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95444						
Packaging information	www.vishay.com/doc?95032						
SPICE model	www.vishay.com/doc?96055						

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIMETERS		INC	INCHES		NOTES		MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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